

## Quad SPST CMOS Analog Switches

### Features

- Low On-Resistance:  $50\ \Omega$
- Low Leakage:  $80\ pA$
- Low Power Consumption:  $0.2\ mW$
- Fast Switching Action— $t_{ON}$ :  $150\ ns$
- Low Charge Injection— $Q$ :  $-1\ pC$
- DG201A/DG202 Upgrades
- TTL/CMOS-Compatible Logic
- Single Supply Capability

### Benefits

- Less Signal Errors and Distortion
- Reduced Power Supply Requirements
- Faster Throughput
- Improved Reliability
- Reduced Pedestal Errors
- Simplifies Retrofit
- Simple Interfacing

### Applications

- Audio Switching
- Battery Powered Systems
- Data Acquisition
- Hi-Rel Systems
- Sample-and-Hold Circuits
- Communication Systems
- Automatic Test Equipment
- Medical Instruments

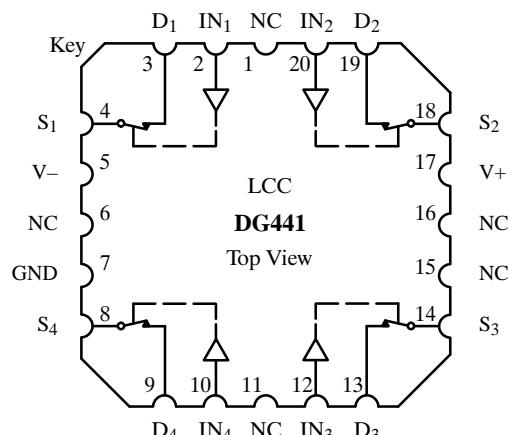
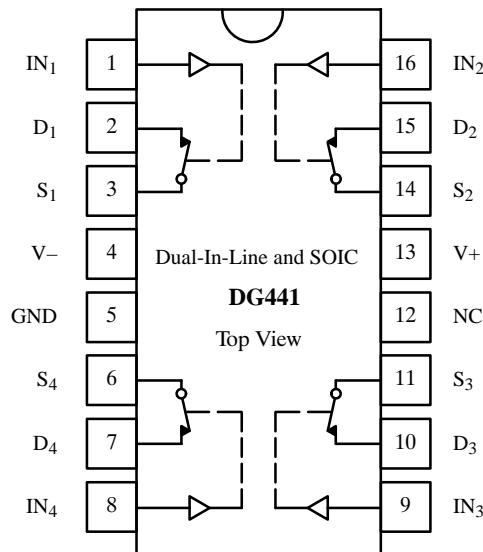
### Description

The DG441/442 monolithic quad analog switches are designed to provide high speed, low error switching of analog and audio signals. The DG441 has a normally closed function. The DG442 has a normally open function. Combining low on-resistance ( $50\ \Omega$ , typ.) with high speed ( $t_{ON}$  150 ns, typ.), the DG441/442 are ideally suited for upgrading DG201A/202 sockets. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

To achieve high voltage ratings and superior switching performance, the DG441/442 are built on Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply levels when off.

### Functional Block Diagram and Pin Configuration



Truth Table

Logic	DG441	DG442
0	ON	OFF
1	OFF	ON

Logic "0"  $\leq 0.8\ V$   
Logic "1"  $\geq 2.4\ V$

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70053.

## Ordering Information

Temp Range	Package	Part Number
-40 to 85°C	16-Pin Plastic DIP	DG441DJ
		DG442DJ
	16-Pin Narrow SOIC	DG441DY
		DG442DY
-55 to 125°C	16-Pin CerDIP	DG441AK
		DG441AK/883
		5962-9204101MEA
		DG442AK
		DG442AK/883
		5962-9204102MEA
	LCC-20	5962-9204101M2A
		5962-9204102M2A

## Absolute Maximum Ratings

V+ to V− ..... 44 V  
 GND to V− ..... 25 V  
 Digital Inputs<sup>a</sup> VS, VD ..... (V−) −2 V to (V+) +2 V  
                                  or 30 mA, whichever occurs first  
 Continuous Current (Any Terminal) ..... 30 mA  
 Current, S or D (Pulsed 1 ms, 10% duty cycle) ..... 100 mA  
 Storage Temperature (AK Suffix) ..... −65 to 150°C  
 (DJ, DY Suffix) ..... −65 to 125°C

Power Dissipation (Package)<sup>b</sup>  
 16-Pin Plastic DIP<sup>c</sup> ..... 450 mW  
 16-Pin CerDIP<sup>d</sup> ..... 900 mW  
 16-Pin Narrow Body SOIC<sup>d</sup> ..... 900 mW  
 LCC-20<sup>d</sup> ..... 1200 mW

### Notes:

- a. Signals on SX, DX, or INX exceeding V+ or V− will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6 mW/°C above 75°C
- d. Derate 12 mW/°C above 25°C

## Schematic Diagram (Typical Channel)

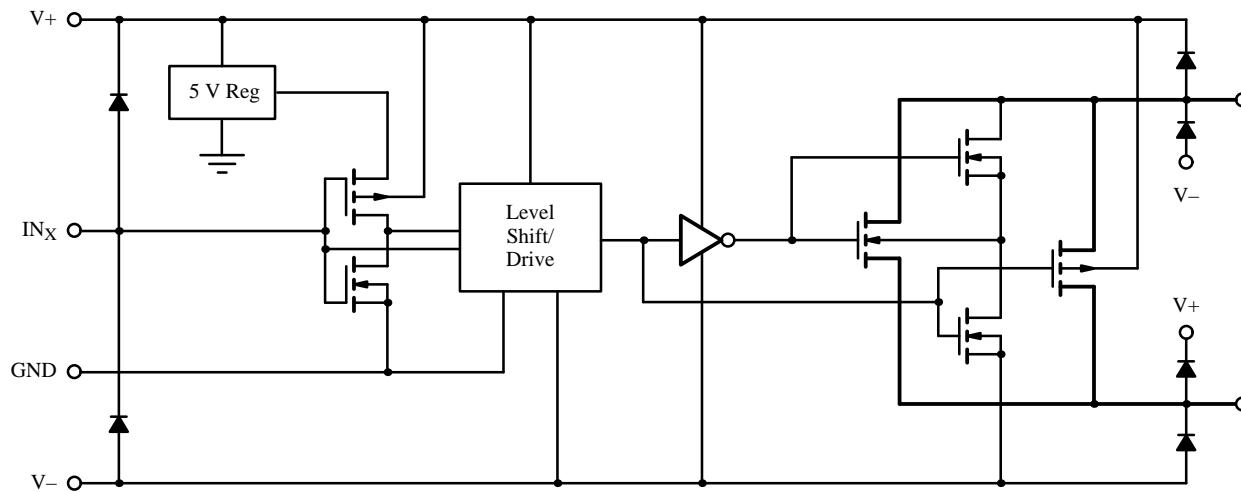


Figure 1.

## Specifications<sup>a</sup> for Dual Supplies

Parameter	Symbol	Test Conditions Unless Specified $V_+ = 15 \text{ V}$ , $V_- = -15 \text{ V}$ $V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		-15	15	-15	15	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10 \text{ mA}$ , $V_D = \pm 8.5 \text{ V}$ $V_+ = 13.5 \text{ V}$ , $V_- = -13.5 \text{ V}$	Room Full	50		85 100		85 100	Ω
Switch Off Leakage Current	$I_{S(off)}$	$V_+ = 16.5 \text{ V}$ , $V_- = -16.5 \text{ V}$ $V_D = \pm 15.5 \text{ V}$ , $V_S = \mp 15.5 \text{ V}$	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	nA
	$I_{D(off)}$		Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	
Channel On Leakage Current	$I_{D(on)}$	$V_+ = 16.5 \text{ V}$ , $V_- = -16.5 \text{ V}$ $V_S = V_D = \pm 15.5 \text{ V}$	Room Full	± 0.08	-0.5 -40	0.5 40	-0.5 -10	0.5 10	
<b>Digital Control</b>									
Input Current $V_{IN}$ Low	$I_{IL}$	$V_{IN}$ under test = 0.8 V All Other = 2.4 V	Full	-0.01	-500	500	-500	500	nA
Input Current $V_{IN}$ High	$I_{IH}$	$V_{IN}$ under test = 2.4 V All Other = 0.8 V	Full	0.01	-500	500	-500	500	
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$ $V_S = \pm 10 \text{ V}$ , See Figure 2	Room	150		250		250	ns
Turn-Off Time	DG441		Room	90		120		120	
	DG442		Room	110		210		210	
Charge Injection <sup>e</sup>	$Q$	$C_L = 1 \text{ nF}$ , $V_S = 0 \text{ V}$ $V_{gen} = 0 \text{ V}$ , $R_{gen} = 0 \Omega$	Room	-1					pC
Off Isolation <sup>e</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ $f = 1 \text{ MHz}$	Room	60					dB
Crosstalk (Channel-to-Channel)	X_TALK		Room	100					
Source Off Capacitance <sup>e</sup>	$C_{S(off)}$	$f = 1 \text{ MHz}$	Room	4					pF
Drain Off Capacitance <sup>e</sup>	$C_{D(off)}$		Room	4					
Channel On Capacitance <sup>e</sup>	$C_{D(on)}$	$V_{ANALOG} = 0 \text{ V}$	Room	16					
<b>Power Supplies</b>									
Positive Supply Current	$I_+$	$V_+ = 16.5 \text{ V}$ , $V_- = -16.5 \text{ V}$ $V_{IN} = 0 \text{ or } 5 \text{ V}$	Full	15		100		100	μA
Negative Supply Current	$I_-$		Room Full	-0.0001	-1 -5		-1 -5		
Ground Current	$I_{GND}$		Full	-15	-100		-100		

Notes:

- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25°C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.

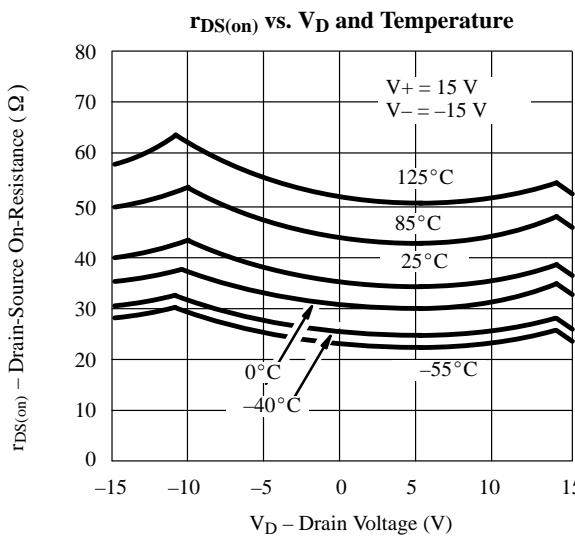
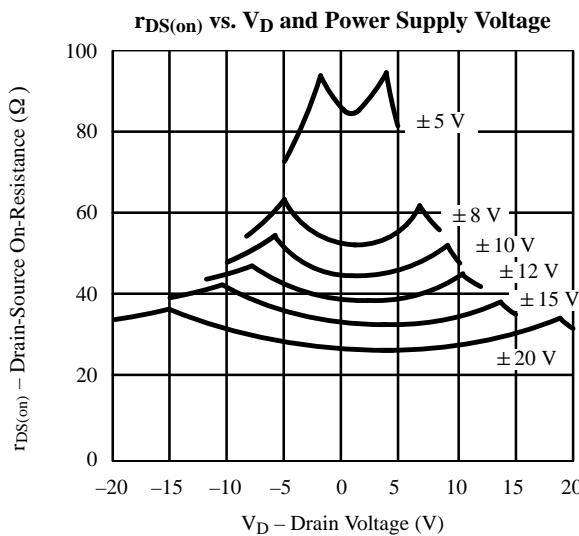
## Specifications<sup>a</sup> for Single Supply

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 12 \text{ V}$ , $V_- = 0 \text{ V}$ $V_{IN} = 2.4 \text{ V}$ , $0.8 \text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		0	12	0	12	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10 \text{ mA}$ , $V_D = 3 \text{ V}$ , $8 \text{ V}$ $V_+ = 10.8 \text{ V}$	Room Full	100		160 200		160 200	Ω
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	$R_L = 1 \text{ kΩ}$ , $C_L = 35 \text{ pF}$ $V_S = 8 \text{ V}$ , See Figure 2	Room	300		450		450	ns
Turn-Off Time	$t_{OFF}$		Room	60		200		200	
Charge Injection	Q	$C_L = 1 \text{ nF}$ $V_{gen} = 6 \text{ V}$ , $R_{gen} = 0 \text{ Ω}$	Room	2					pC
<b>Power Supplies</b>									
Positive Supply Current	$I_+$	$V_+ = 16.5 \text{ V}$ , $V_- = -16.5 \text{ V}$ $V_{IN} = 0$ or $5 \text{ V}$	Full	15		100		100	μA
Negative Supply Current	$I_-$		Room Full	-0.0001 -100	-1 -100		-1 -100		
Ground Current	$I_{GND}$		Full	-15	-100		-100		

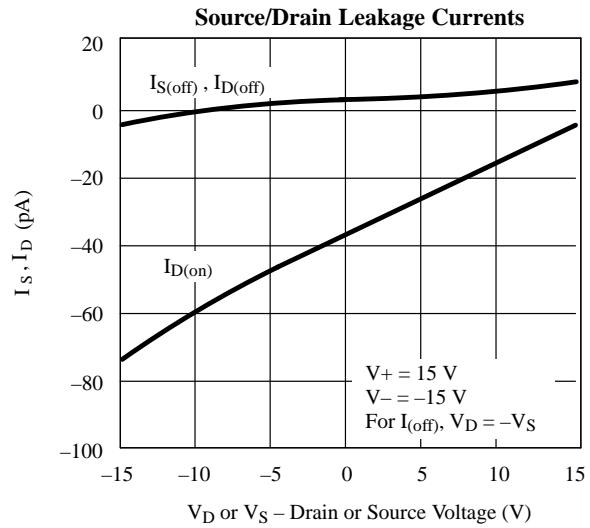
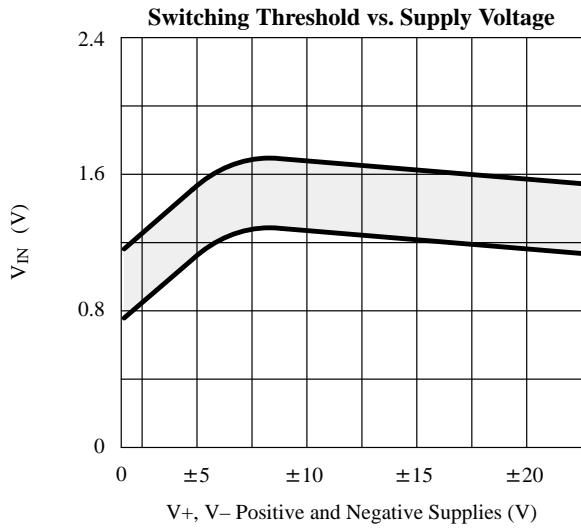
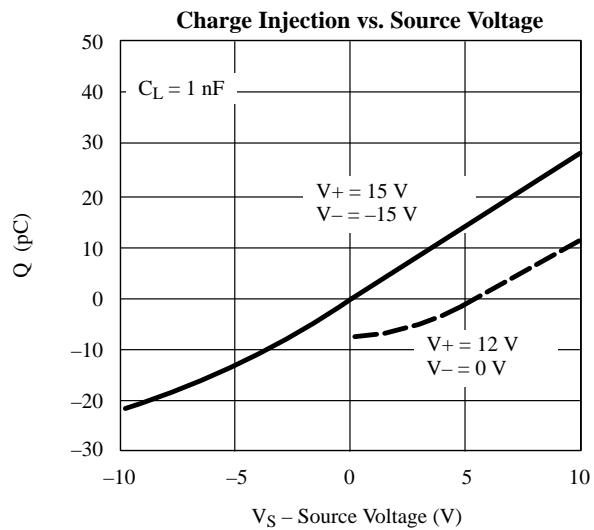
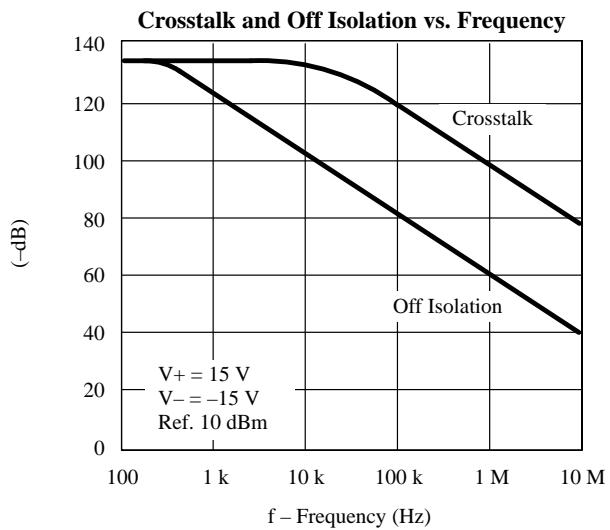
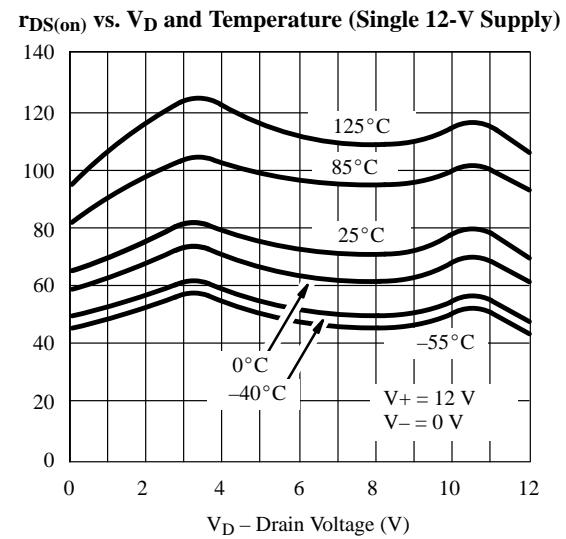
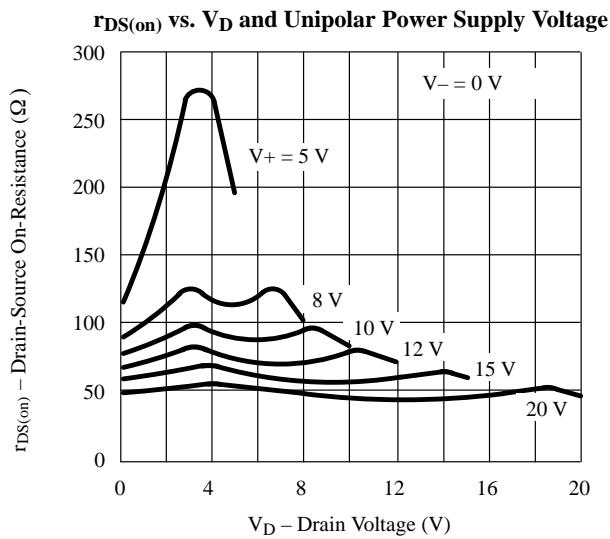
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## Typical Characteristics

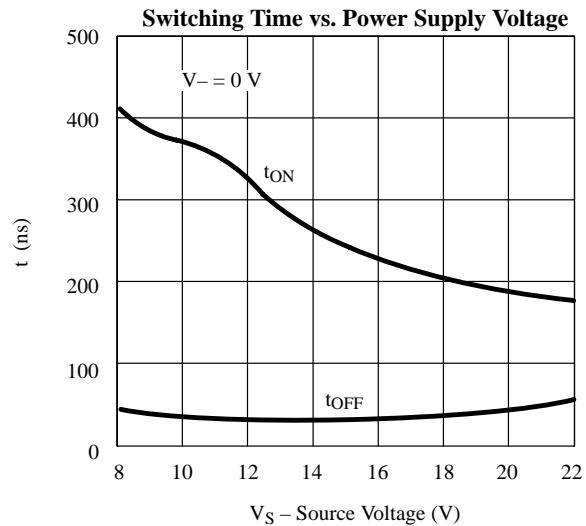
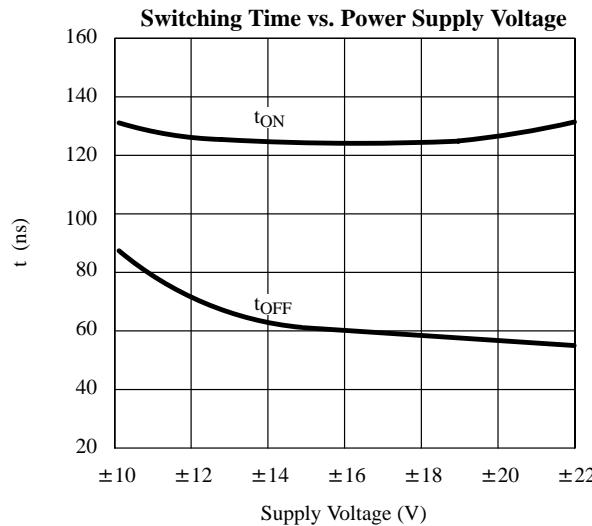
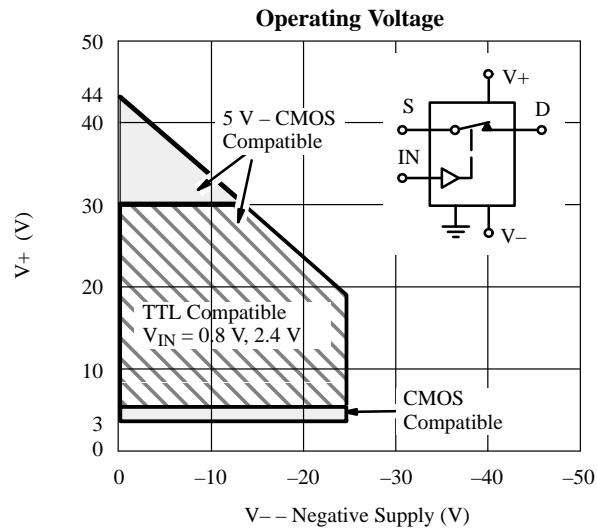
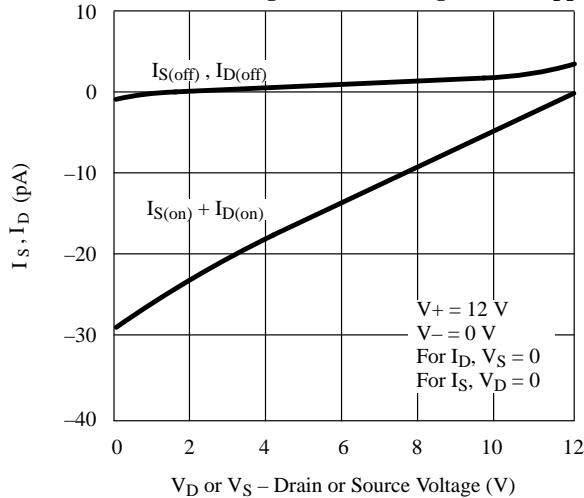


## Typical Characteristics (Cont'd)

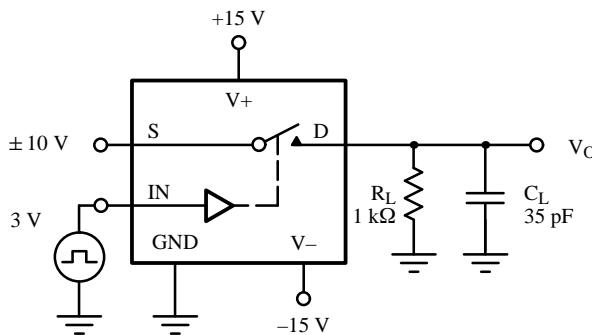


## Typical Characteristics (Cont'd)

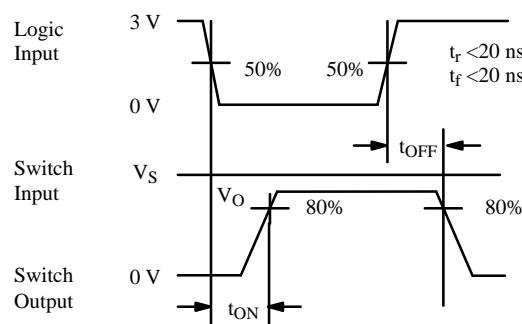
Source/Drain Leakage Currents (Single 12-V Supply)



## Test Circuits



$C_L$  (includes fixture and stray capacitance)



Note: Logic input waveform is inverted for DG442.

Figure 2. Switching Time

## Test Circuits (Cont'd)

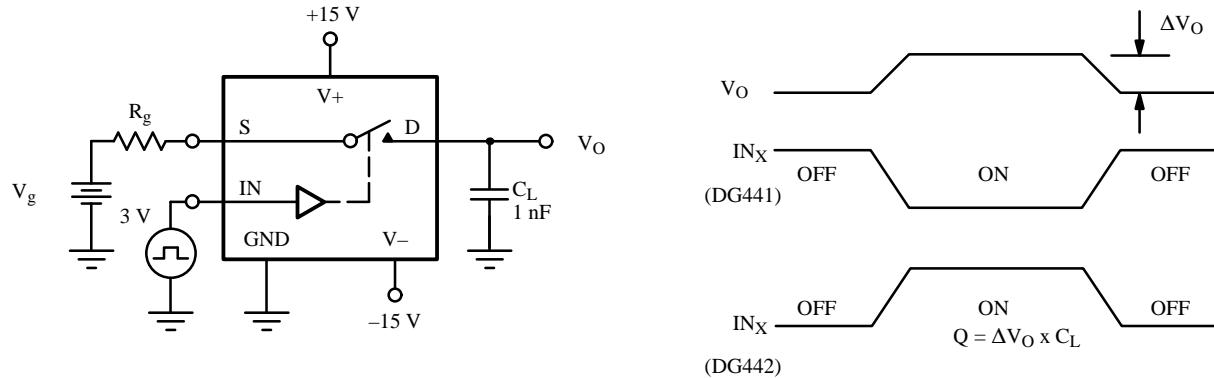


Figure 3. Charge Injection

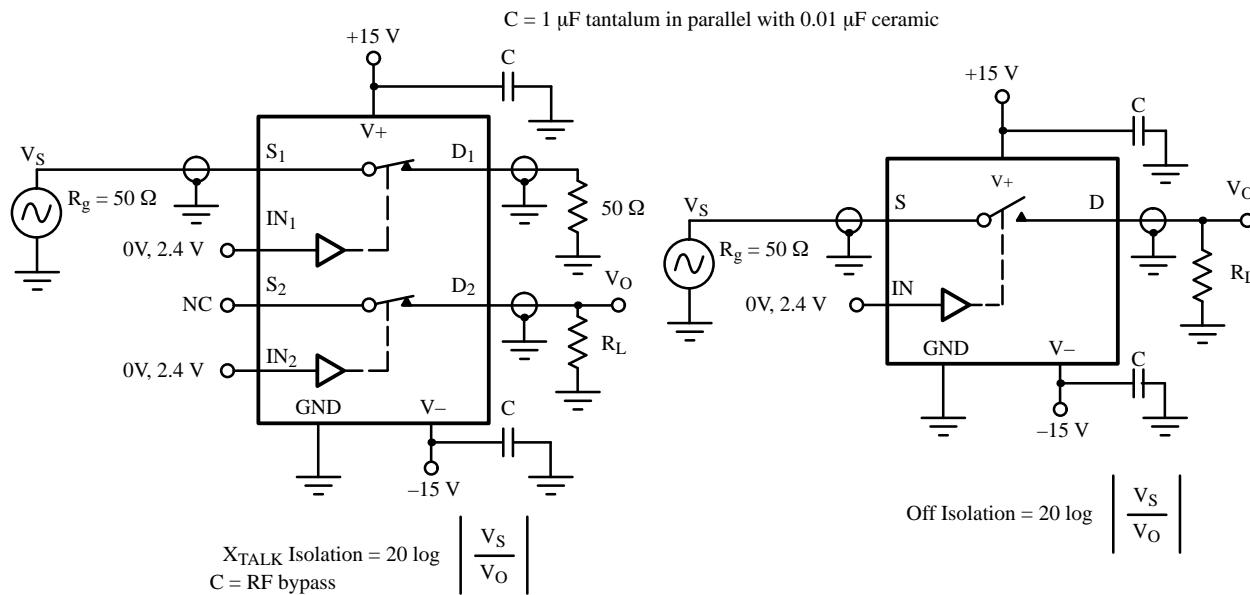


Figure 4. Crosstalk

Figure 5. Off Isolation

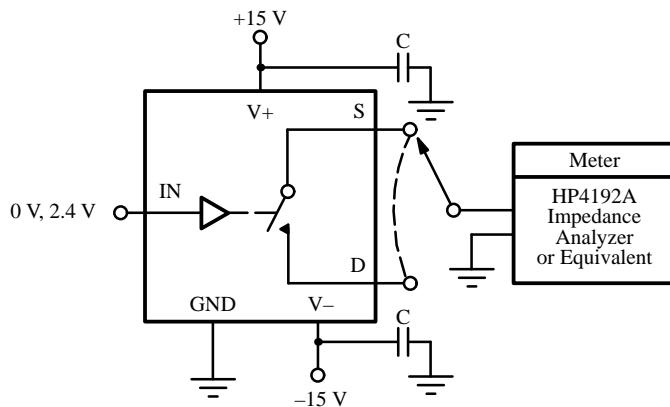
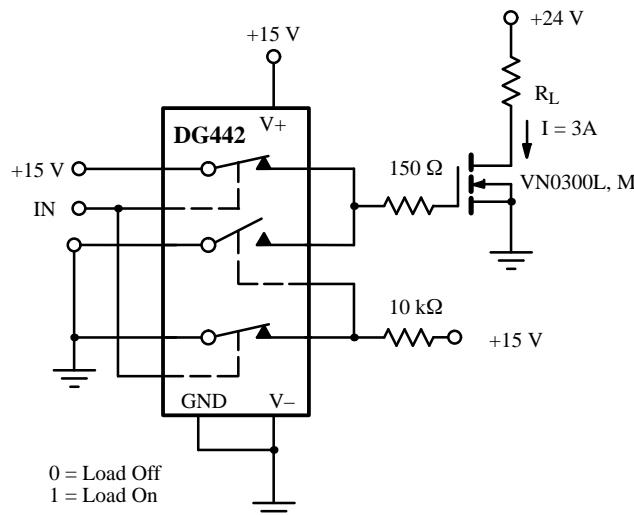
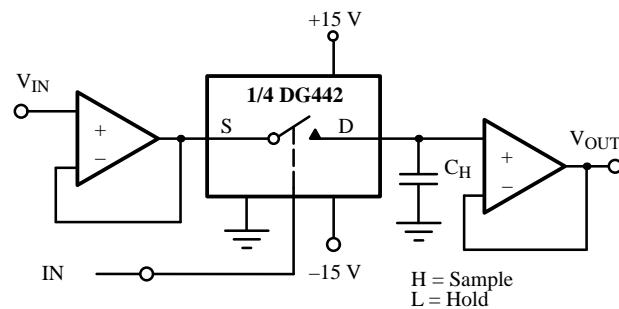


Figure 6. Source/Drain Capacitances

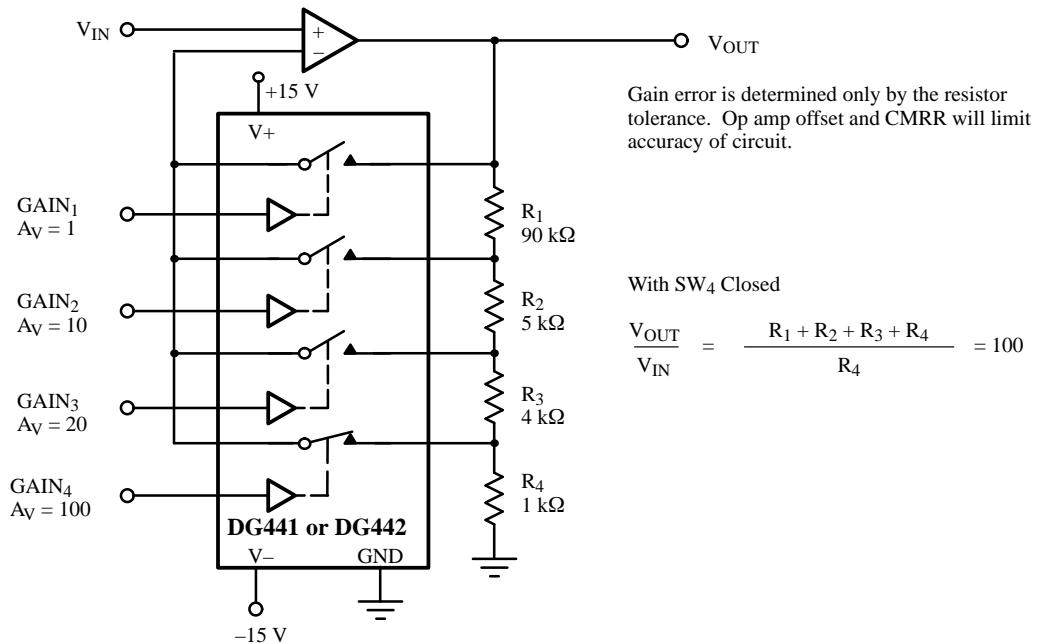
## Applications



**Figure 7.** Power MOSFET Driver



**Figure 8.** Open Loop Sample-and-Hold



**Figure 9.** Precision-Weighted Resistor Programmable-Gain Amplifier